

N-CHANNEL ENHANCEMENT MODE MOSFET

DMG2302UQ

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
20V	90mΩ @V _{GS} = 4.5V	4.2A
	120mΩ @V _{GS} = 2.5V	2.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General purpose interfacing switches
- Power management functions
- Boost applications
- Analog switches

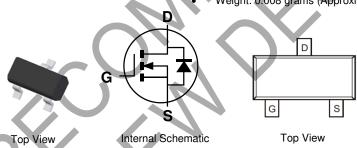
Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMG2302UQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe, Solderable per MIL-STD-202, Method 208 (e3) Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Package	Packing		
Part Nulliber	Раскауе	Qty.	Carrier	
DMG2302UQ-7	SOT23	3,000	Tape & Reel	
DMG2302UQ-13	SOT23	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes: See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

G23	MY			

G23 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 8 = August)

Date Code Key												
Year	2015		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	С		J	K	L	М	N	0	Р	R	S	Т
Month	lan	Fob	Mar	Apr	Мау	lun	hul	Διια	Sen	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Units
Drain-Source Voltage			VDSS	20	V
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	ID	4.2 3.4	А	
Pulsed Drain Current (Note 6)			ldм	27	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)	「A = +25°C 「A = +70°C	Po	0.8 0.5	W
Thermal Resistance, Junction to Ambient @T _A = +25°C		R _{0JA}	156	°C/W
Operating and Storage Temperature Range		Tj, Tstg	-55 to +150	℃

 Notes:
 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

 6. Repetitive rating, pulse width limited by junction temperature.

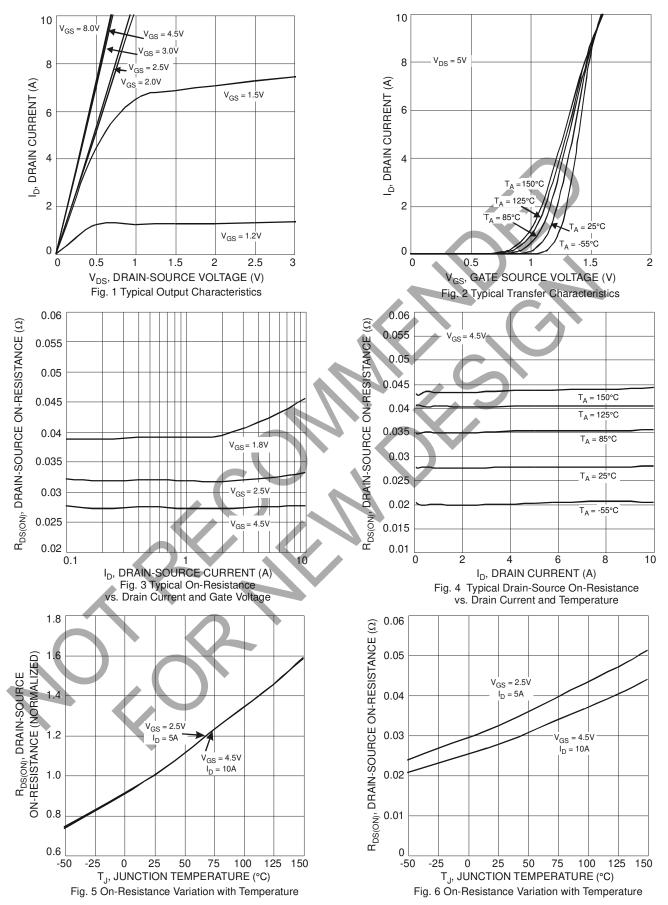
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	20	_		V	$V_{GS} = 0V$, $I_D = 10\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	IDSS		1(1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	lgss			±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.4	Ļ	1.0	V	$V_{DS} = V_{GS}$, $I_D = 50 \mu A$
Static Drain-Source On-Resistance	Proven			90	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$
Static Drain-Source On-Resistance	RDS(ON)			120	11122	$V_{GS} = 2.5V, I_D = 3.1A$
Forward Transfer Admittance	Y _{fs}	I	13	_	S	$V_{DS} = 5V, I_D = 3.6A$
Diode Forward Voltage	Vsd		0.75	1.0	V	$V_{GS} = 0V$, $I_S = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	594.3		рF	
Output Capacitance	Coss	_	64.5		рF	V _{DS} = 10V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	57.7	—	pF	1 - 1.00012
Gate Resistance	Rg	—	1.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	—	7.0	_	nC	
Gate-Source Charge	Q _{gs}	—	0.9	_	nC	VGS = 4.5V, VDS = 10V, ID = 3.6A
Gate-Drain Charge	Qgd	—	1.4	_	nC	ID = 3.6A
Turn-On Delay Time	tD(on)	—	7.4	—	ns	
Turn-On Rise Time	tr	—	9.8	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	tD(off)	—	28.1	—	ns	$R_L = 2.78\Omega, R_G = 1.0\Omega$
Turn-Off Fall Time	tr	_	6.7		ns	

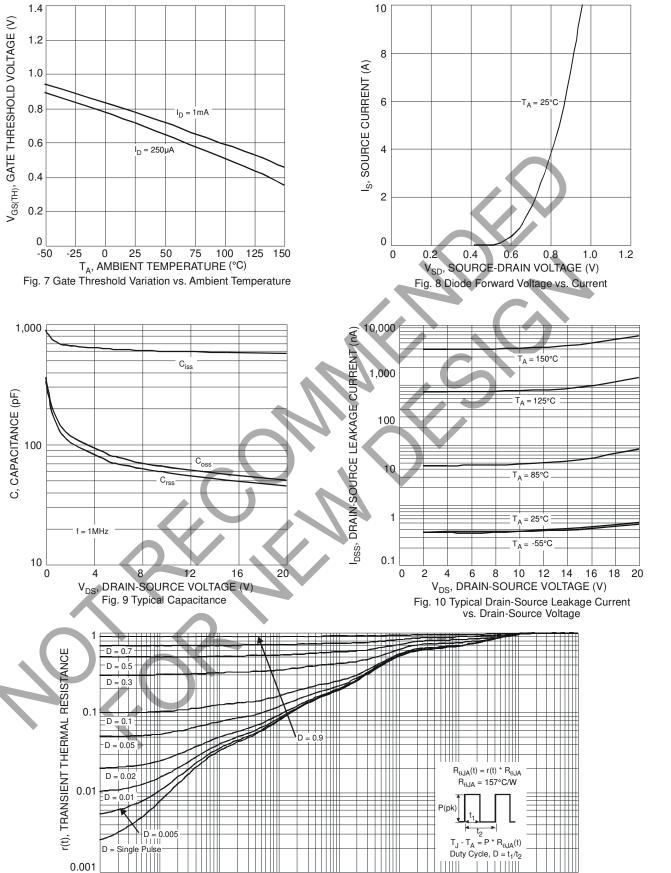
Notes:7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.



DMG2302UQ







0.00001

0.0001

0.001

0.01

0.1

t₁, PULSE DURATION TIME (s) Fig. 11 Transient Thermal Response 10

100

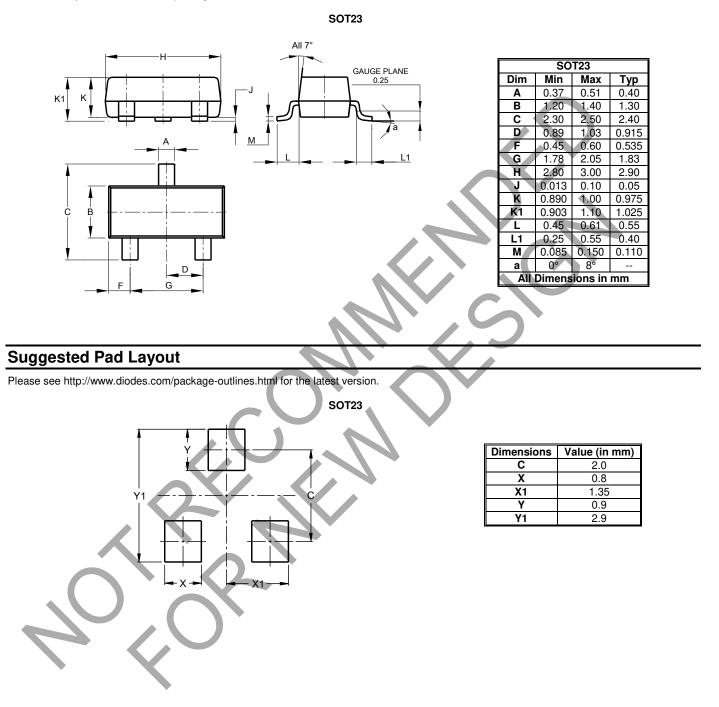
1,000

DMG2302UQ



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





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